General purpose transistor (isolated transistor and diode) QSL12

A 2SD2675 and a RB461F are housed independently in a TSMT5 package.

Applications

DC / DC converter Motor driver

Features

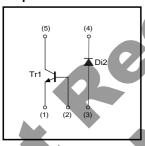
1) Tr : Low Vce(sat) Di : Low Vr

2) Small package

Structure

Silicon epitaxial planar transistor Schottky barrier diode

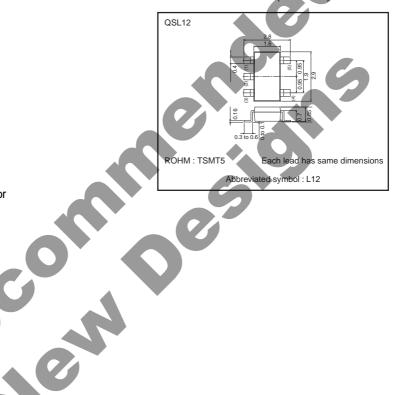
●Equivalent circuit



Packaging specifications

Туре	QSL12		
Package	TSMT5		
Marking	L12		
Code	TR		
Basic ordering unit(pieces)	3000		

●External dimensions (Unit: mm)



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	30	V
Collector-emitter voltage	Vceo	30	V
Emitter-base voltage	VEBO	6	V
Collector current	Ic	1	A
	ICP	2	A *1
Power dissipation	Pc	0.9	W/ELEMENT *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-40 to +125	°C

Di2

Parameter	Symbol	Limits	Unit
Peak reverse voltage	VRM	25	V
Reverse voltage (DC)	VR	20	V
Average rectified forward current	lF	700	mA
Forward current surge peak (60Hz, 1∞)	IFSM	3	A
Power dissipation	P□	0.7	W/ELEMENT *
Junction temperature	Tj	125	°C
Range of storage temperature	Tstg	-40 to +125	°C

^{*} Mounted on a 25mm×25mm×10.8mm ceramic substrate

Tr1&Di2

Parameter	Symbol	Limits	Unit
Total power disipation	PD	0.5	W/TOTAL *1
		1.25	W/TOTAL *2

^{*1} Each terminal mounted on a recommended land. *2 Mounted on a 25mm×25mm×10.8mm ceramic substrate

●Electrical characteristics (Ta=25°C)

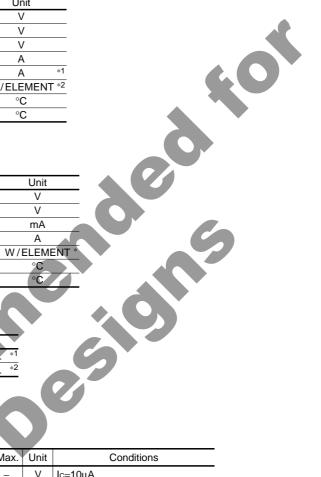
Tr1

111	4					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	30	-	_	V	Ic=10μA
Collector-emitter breakdown voltage	BVceo	30		_	V	Ic=1mA
Emitter-base breakdown voltage	ВУЕВО	6	-	_	V	Iε=10μA
Collector cutoff current	Ісво	1	-	100	nA	Vcb=30V
Emitter cutoff current	ІЕВО	_	_	100	nA	V _{EB} =6V
Collector-emitter saturation voltage	VCE(sat)	_	120	350	mV	Ic/I _B =500mA/25mA
DC current gain	hfe	270	_	680	_	Vce/lc=2V/100mA *
Transition frequency	f⊤	_	320	_	MHz	VcE=2V, IE=-100mA, f=100MHz*
Collector output capacitance	Cob	_	7	_	pF	Vcb=10V, Ie=0A, f=1MHz

[·] Pulsed

Di2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	450	490	mV	I _F =700mA
Reverse current	I R	-	_	200	μΑ	V _R =20V
Reverse recovery fime	trr	_	9	_	ns	IF=IR=100mA, Irr=0.1IR



Rev.A

^{*1} Single pulse, Pw=1ms *2 Mounted on a 25mm×25mm×¹0.8mm ceramic substrate

•Electrical characteristic curves

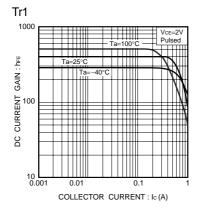


Fig.1 DC current gain vs. collector current

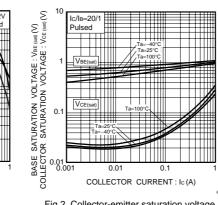


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

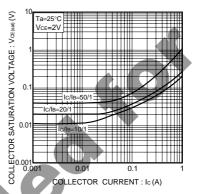


Fig.3 Collector-emitter saturation voltage vs. collector current

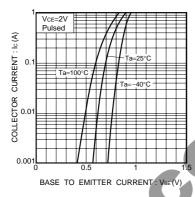


Fig.4 Grounded emitter propagation characteristics

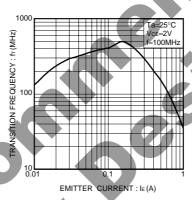


Fig.5 Gain bandwidth product vs. emitter current

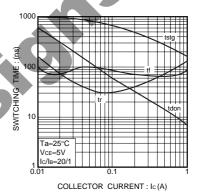


Fig.6 Switching time

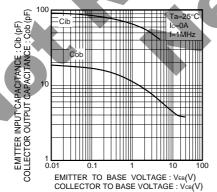
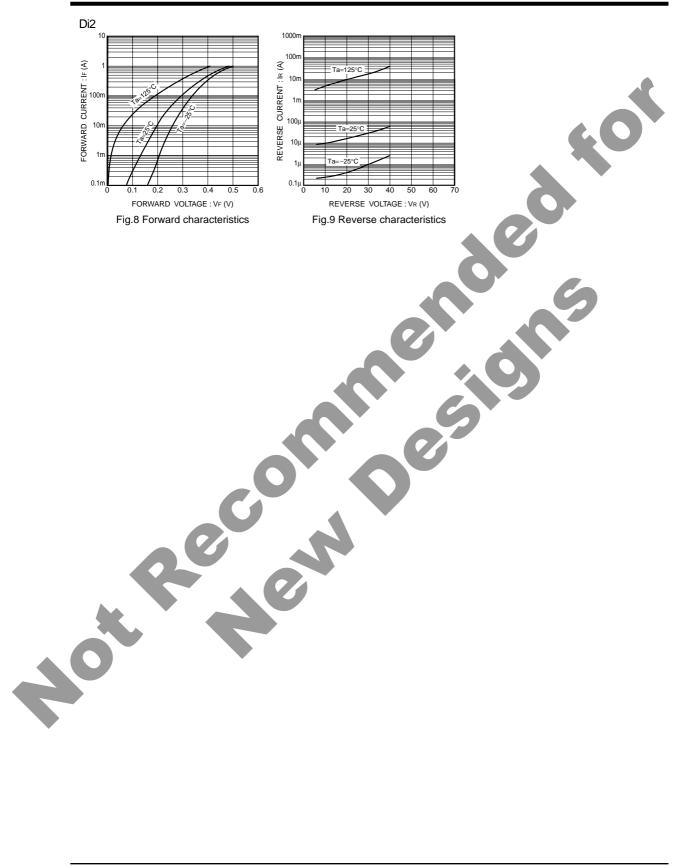


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage





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